

# SEMICONDUCTOR TECHNICAL DATA

## **MJE13007F**

#### TRIPLE DIFFUSED NPN TRANSISTOR

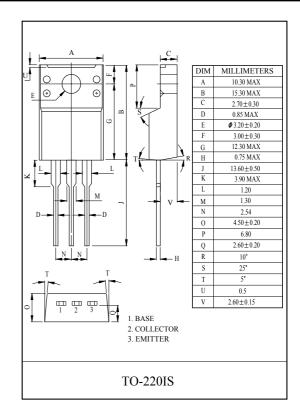
SWITCHING REGULATOR APPLICATION. HIGH VOLTAGE SWITCHING APPLICATION. HIGH SPEED DC-DC CONVERTER APPLICATION.

#### **FEATURES**

- · Excellent Switching Times
  - :  $t_{on}=1.6\mu S(Max.)$ ,  $t_f=0.7\mu S(Max.)$ , at  $I_C=5A$
- · High Collector Voltage : V<sub>CBO</sub>=700V.

### MAXIMUM RATING (Ta=25°C)

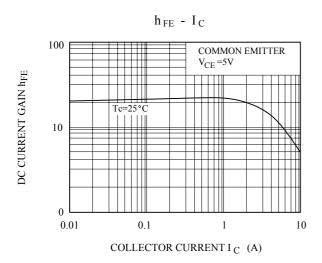
| CHARACTERISTIC                       |       | SYMBOL           | RATING  | UNIT          |  |
|--------------------------------------|-------|------------------|---------|---------------|--|
| Collector-Base Voltage               |       | V <sub>CBO</sub> | 700     | V             |  |
| Collector-Emitter Voltage            |       | V <sub>CEO</sub> | 400     | V             |  |
| Emitter-Base Voltage                 |       | $V_{\rm EBO}$    | 9       | V             |  |
| Collector Current                    | DC    | $I_{C}$          | 8       | A             |  |
|                                      | Pulse | I <sub>CP</sub>  | 16      |               |  |
| Base Current                         |       | $I_{\mathrm{B}}$ | 4       | A             |  |
| Collector Power Dissipation (Tc=25℃) |       | $P_{\rm C}$      | 40      | W             |  |
| Junction Temperature                 |       | T <sub>j</sub>   | 150     | ${\mathbb C}$ |  |
| Storage Temperature Range            |       | $T_{stg}$        | -55~150 | ${\mathbb C}$ |  |

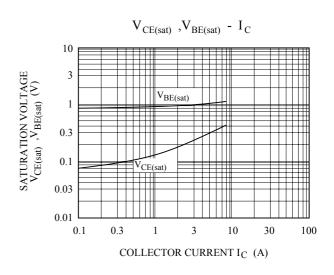


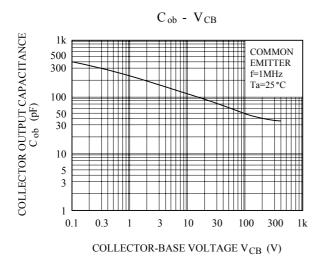
#### ELECTRICAL CHARACTERISTICS (Ta=25°C)

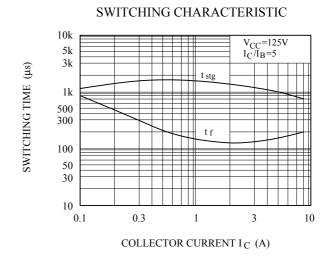
| CHARACTERISTIC                       | SYMBOL                          | TEST CONDITION   | MIN. | TYP. | MAX. | UNIT |  |
|--------------------------------------|---------------------------------|--|------|------|------|------|--|
| Emitter Cut-off Current              | $I_{EBO}$                       | $V_{EB}=9V, I_{C}=0$   | -    | -    | 1    | mA   |  |
| DC Current Gain                      | h <sub>FE</sub> (1)             | $V_{CE}=5V$ , $I_{C}=2A$   | 19   | -    | 36   |      |  |
|                                      | h <sub>FE</sub> (2)             | $V_{CE}=5V$ , $I_{C}=5A$   | 10   | -    | 30   |      |  |
| Collector-Emitter Saturation Voltage | V <sub>CE(sat)</sub>            | $I_{C}=2A, I_{B}=0.4A$   | -    | -    | 1    | V    |  |
|                                      |                                 | $I_{C}=5A, I_{B}=1A$   | -    | -    | 2    |      |  |
|                                      |                                 | $I_{C}=8A, I_{B}=2A$   | -    | -    | 3    |      |  |
| Base-Emitter Saturation Voltage      | $V_{\mathrm{BE}(\mathrm{sat})}$ | $I_{C}=2A, I_{B}=0.4A$   | -    | -    | 1.5  | - V  |  |
|                                      |                                 | $I_{C}=5A, I_{B}=1A$   | -    | -    | 1.6  | ·    |  |
| Collector Output Capacitance         | C <sub>ob</sub>                 | $V_{CB}$ =10V, f=0.1MHz, $I_{E}$ =0  | -    | 110  | -    | pF   |  |
| Transition Frequency                 | $f_T$                           | $V_{CE}=10V, I_{C}=0.5A$   | 4    | -    | -    | MHz  |  |
| Turn-On Time                         | t <sub>on</sub>                 | $I_{B1} \longrightarrow I_{B2} \longrightarrow I$ | -    | -    | 1.6  | μS   |  |
| Storage Time                         | $t_{\mathrm{stg}}$              |  | -    | -    | 3    | μS   |  |
| Fall Time                            | $t_{\mathrm{f}}$                | $I_{\rm B1} = I_{\rm B2} = 1  {\rm Mm}  \begin{tabular}{ll} & & & & \\ & & & & \\ & & & & \\ & & & & $   | -    | -    | 0.7  | μS   |  |

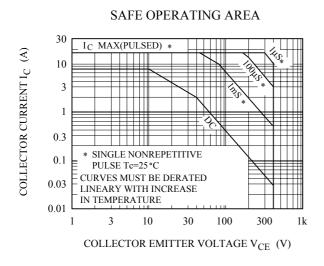
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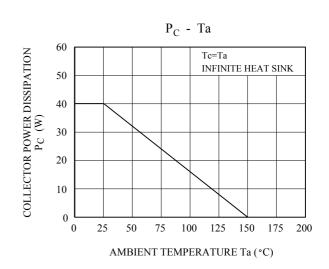












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